

## N-Channel 100 V (D-S) MOSFET

PRODUCT SUMMARY		
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A)
100	0.084 at V <sub>GS</sub> = 10 V	6
	0.095 at V <sub>GS</sub> = 4.5 V	4.5

### FEATURES

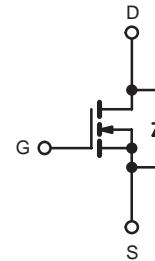
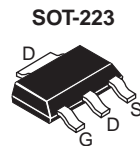
- TrenchFET Power MOSFETs
- 100% R<sub>g</sub> and UIS Tested

### APPLICATIONS

- Synchronous Rectification in DC/DC and AC/DC Converters
- Industrial and Motor Drive applications



**RoHS**  
COMPLIANT



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T <sub>A</sub> = 25 °C, unless otherwise noted					
Parameter	Symbol	10 s	Steady State	Unit	
Drain-Source Voltage	V <sub>DS</sub>	100		V	
Gate-Source Voltage	V <sub>GS</sub>	± 20			
Continuous Drain Current (T <sub>J</sub> = 175 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C T <sub>A</sub> = 70 °C	I <sub>D</sub>	6.0	4.0	A
			3.6	3.1	
Pulsed Drain Current	I <sub>DM</sub>	24			
Avalanche Current	I <sub>AS</sub>	18			
Single Pulse Avalanche Energy	E <sub>AS</sub>	21		mJ	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 25 °C T <sub>A</sub> = 70 °C	P <sub>D</sub>	4.0	1.9	W
			2.6	1.5	
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	- 55 to 175		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>a</sup>	t ≤ 10 s	R <sub>thJA</sub>	36	45	°C/W
	Steady State		75	90	
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	17	20	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

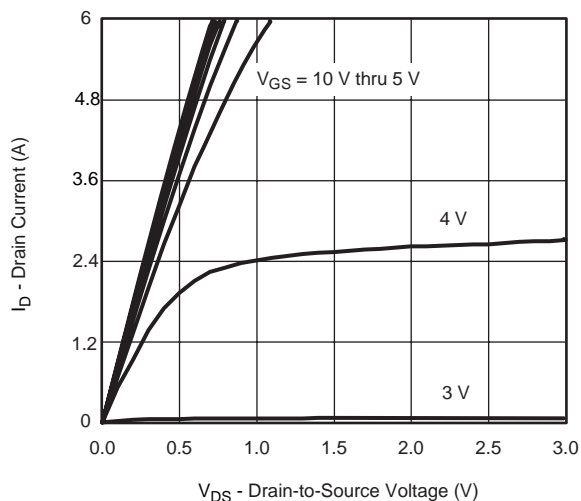
<b>SPECIFICATIONS</b> $T_J = 25\text{ }^\circ\text{C}$ , unless otherwise noted						
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>Static</b>						
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS} = 0\text{ V}, I_D = 250\text{ }\mu\text{A}$	100			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\text{ }\mu\text{A}$	1		3	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 80\text{ V}, V_{GS} = 0\text{ V}$			1	$\mu\text{A}$
		$V_{DS} = 80\text{ V}, V_{GS} = 0\text{ V}, T_J = 55\text{ }^\circ\text{C}$			20	
On-State Drain Current <sup>a</sup>	$I_{D(on)}$	$V_{DS} \geq 5\text{ V}, V_{GS} = 10\text{ V}$	20			A
Drain-Source On-State Resistance <sup>a</sup>	$R_{DS(on)}$	$V_{GS} = 10\text{ V}, I_D = 3.0\text{ A}$		0.084	0.093	$\Omega$
		$V_{GS} = 10\text{ V}, I_D = 2.5\text{ A}, T_J = 125\text{ }^\circ\text{C}$		0.090	0.096	
		$V_{GS} = 10\text{ V}, I_D = 2.0\text{ A}, T_J = 175\text{ }^\circ\text{C}$		0.105	0.120	
		$V_{GS} = 4.5\text{ V}, I_D = 2.0\text{ A}$		0.095	0.110	
Forward Transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = 80\text{ V}, I_D = 3.0\text{ A}$		17		S
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_S = 2.0\text{ A}, V_{GS} = 0\text{ V}$		0.8	1.2	V
<b>Dynamic<sup>b</sup></b>						
Total Gate Charge	$Q_g$	$V_{DS} = 80\text{ V}, V_{GS} = 10\text{ V}, I_D = 3.0\text{ A}$		18		nC
Gate-Source Charge	$Q_{gs}$			5.4		
Gate-Drain Charge	$Q_{gd}$			2.3		
Gate Resistance	$R_g$	$V_{GS} = 0.1\text{ V}, f = 5\text{ MHz}$		2.4		$\Omega$
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 80\text{ V}, R_L = 30\text{ }\Omega$ $I_D \cong 3\text{ A}, V_{GEN} = 10\text{ V}, R_g = 6\text{ }\Omega$		7		ns
Rise Time	$t_r$			4		
Turn-Off Delay Time	$t_{d(off)}$			25		
Fall Time	$t_f$			5		
Source-Drain Reverse Recovery Time	$t_{rr}$	$I_F = 1.5\text{ A}, dI/dt = 100\text{ A}/\mu\text{s}$		40		

Notes:

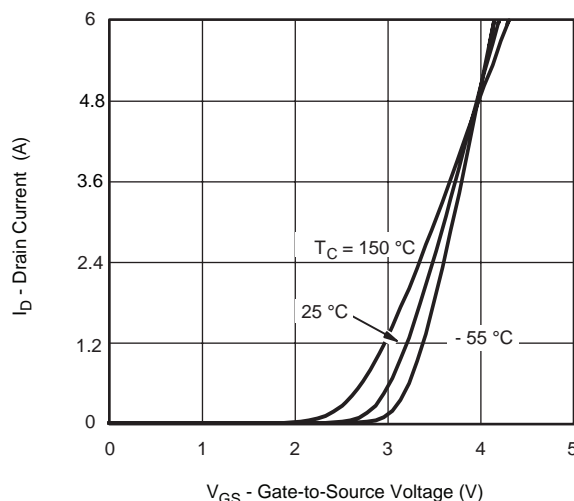
- a. Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**TYPICAL CHARACTERISTICS**  $25\text{ }^\circ\text{C}$ , unless otherwise noted

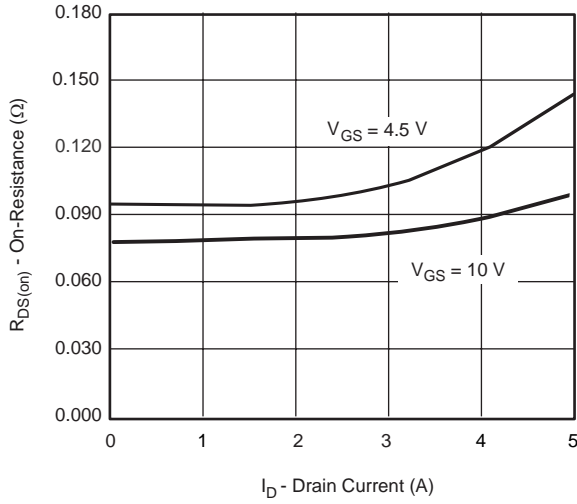


**Output Characteristics**

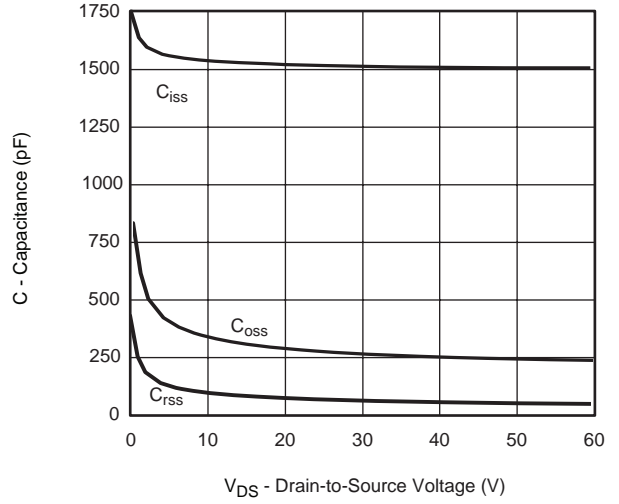


**Transfer Characteristics**

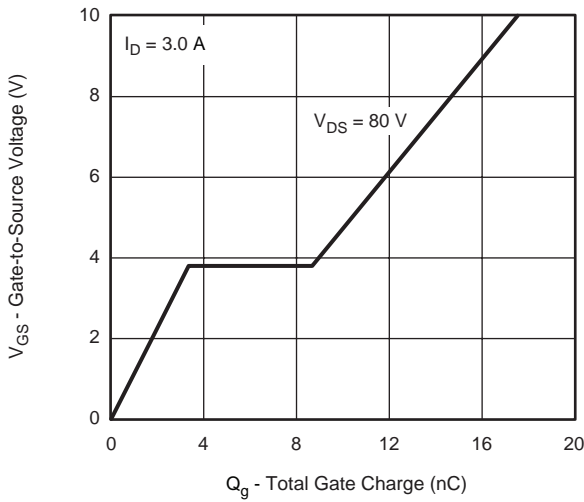
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



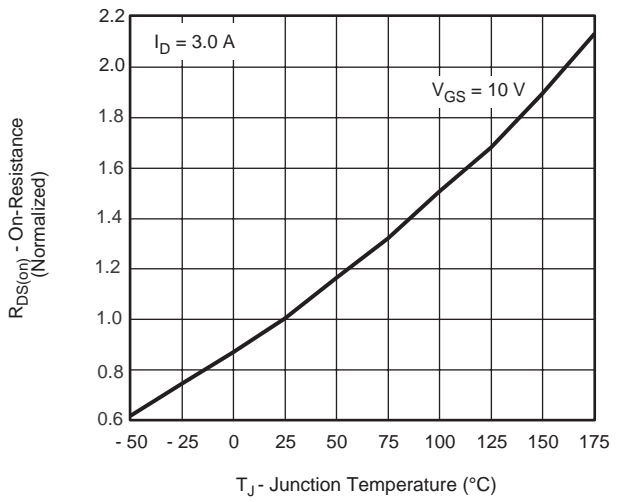
**On-Resistance vs. Drain Current**



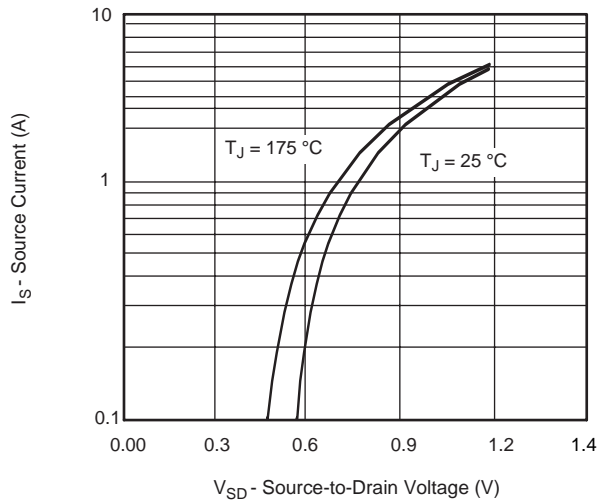
**Capacitance**



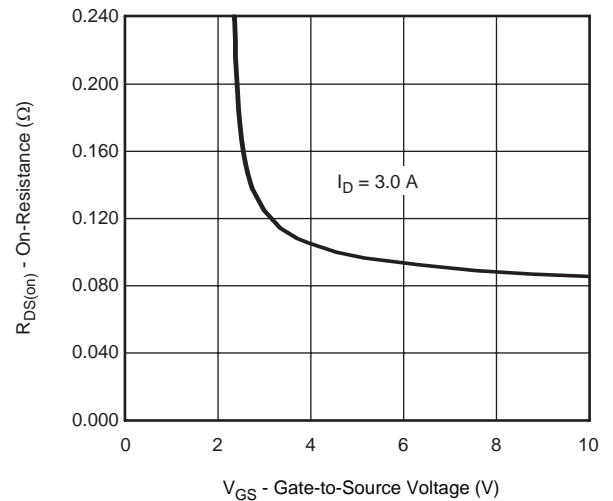
**Gate Charge**



**On-Resistance vs. Junction Temperature**

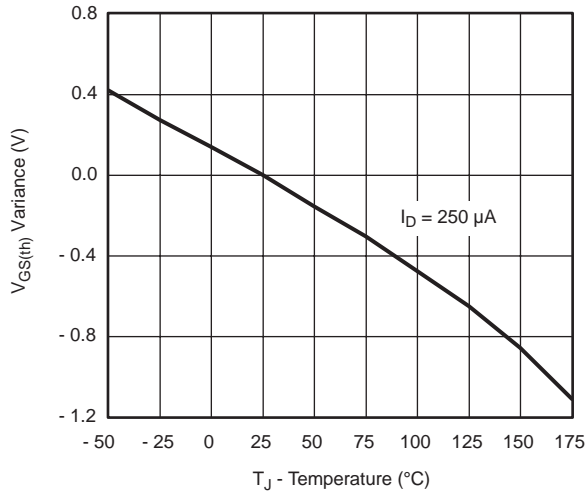


**Source-Drain Diode Forward Voltage**

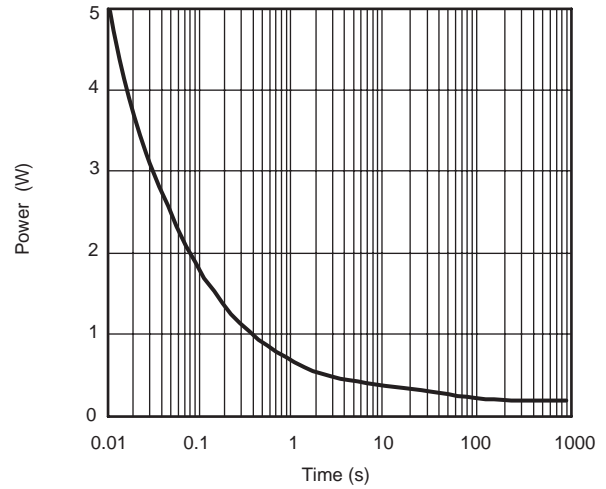


**On-Resistance vs. Gate-to-Source Voltage**

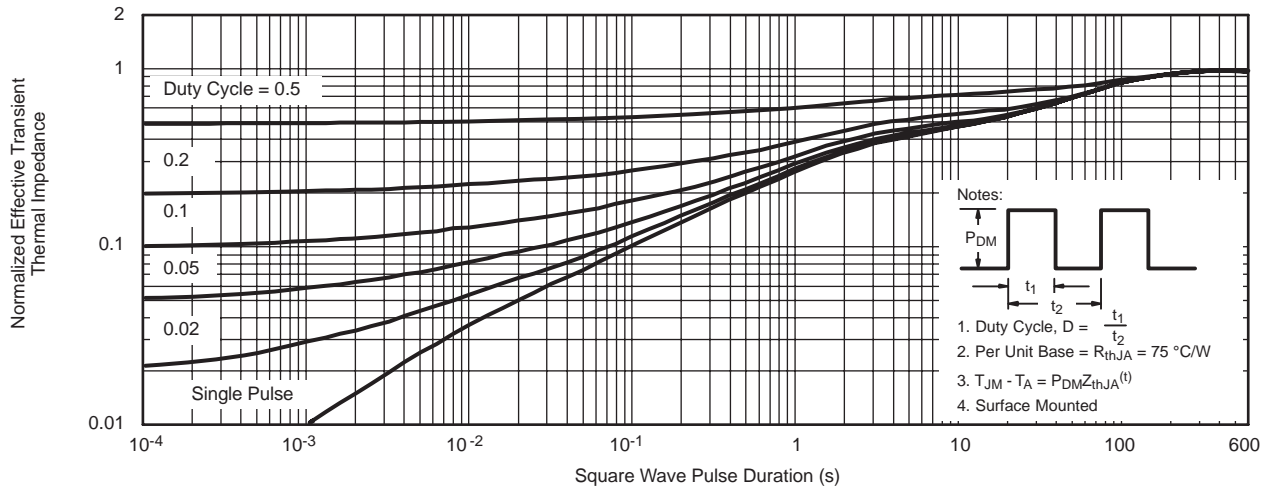
**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



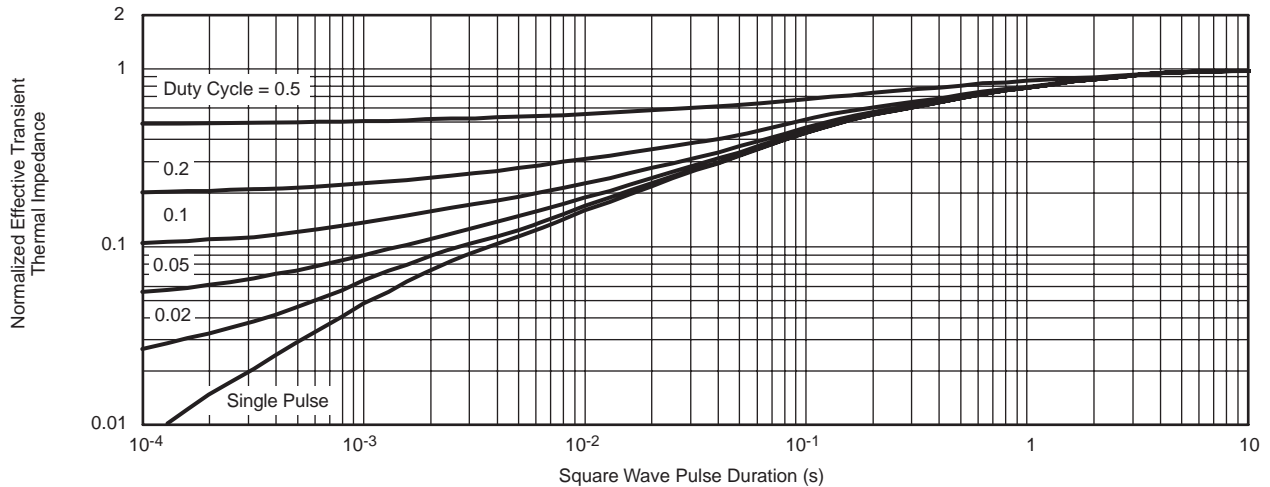
**Threshold Voltage**



**Single Pulse Power**

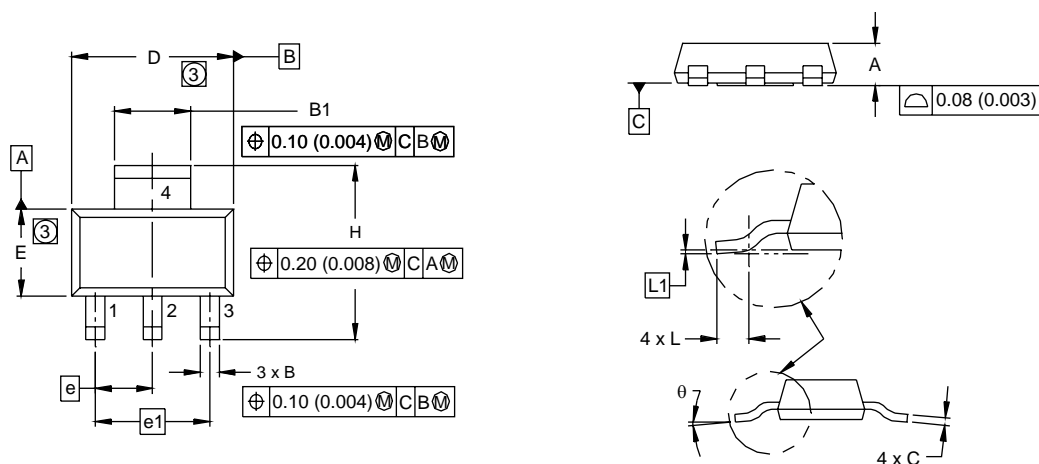


**Normalized Thermal Transient Impedance, Junction-to-Ambient**



**Normalized Thermal Transient Impedance, Junction-to-Foot**

**SOT-223 (HIGH VOLTAGE)**



DIM.	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	1.55	1.80	0.061	0.071
B	0.65	0.85	0.026	0.033
B1	2.95	3.15	0.116	0.124
C	0.25	0.35	0.010	0.014
D	6.30	6.70	0.248	0.264
E	3.30	3.70	0.130	0.146
e	2.30 BSC		0.0905 BSC	
e1	4.60 BSC		0.181 BSC	
H	6.71	7.29	0.264	0.287
L	0.91	-	0.036	-
L1	0.061 BSC		0.0024 BSC	
$\theta$	-	10'	-	10'

ECN: S-82109-Rev. A, 15-Sep-08  
DWG: 5969

**Notes**

1. Dimensioning and tolerancing per ASME Y14.5M-1994.
2. Dimensions are shown in millimeters (inches).
3. Dimension do not include mold flash.
4. Outline conforms to JEDEC outline TO-261AA.

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